Abstract— this paper presents design and simulation of tunable microwave capacitor based on microfluidic actuation. The structure modeling shows an important variation of electric field and current distribution following the DI water displacement in microchannels. In addition, the capacitance value is comprised between $C_{\text{min}} = 0.11 \text{ pF}$ and $C_{\text{max}} = 5.76 \text{ pF}$ allowing a very wide variation that reaches $\text{Tr} = 5136\%$ at 4.5 GHz. Furthermore, the resonant frequency ranges from 5.67 GHz to 19.81 GHz and we obtain a broad band ability higher than 240%. The maximum quality factor value $Q_{\text{max}} = 84.27$ results when the capacitor is empty and degrades to $Q_{\text{min}} = 3.99$ when it is fully filled with DI water at 4.5 GHz.

Keywords—Microfluidic; RF MEMS, capacitor; tunable; wide band.

I. INTRODUCTION

RF MEMS capacitors play a major role in telecommunications systems. They are used in multitude RF applications such as: wireless networks, radar systems, cellular telephony, and satellite communication. The main features involved in the design of variable RF MEMS capacitors are: high tuning range, low insertion loss, high quality factor, broadband, high frequency operation. The versatility of actuation modes of RF MEMS capacitors enables several essential functions such as impedance matching, adjustable filters, variable phase shifters, multi-band amplifiers or adjustable amplifiers.

Originally, actuations modes are based on operating forces generated due to the conversion of mechanical energy into electrical energy and vice versa. However, the implantation of an actuator to the micrometer scale requires specific manufacturing techniques and materials. The most important feature in RF MEMS capacitors is variation range, which is usually related to the nature of the used mode. Since the invention of MEMS components the researchers have tried to cross the limits of variation based on different actuations modes [1-6].

In this paper, we present a high tunable RF MEMS capacitor based on microfluidic actuation. In the section, we present the 3D perspective of our microfluidic capacitor and our principal of variation. In the next section, we study the electric field and current distribution following the DI water displacement. In third section, we investigate the effect of fluidic variation on capacitance and quality factor in response of frequency. Finally, we analyze the RF performances of our capacitor: resonant frequency and insertion loss, in response DI water displacement in microchannels.

II. MICROFLUIDIC CAPACITOR DESIGN:

Our principle of variation relies on the modification of driving medium permittivity where prevailing electric field following DI water displacement between capacitor’s electrodes. The change will take place gradually and continuously as a function of dielectric fluid passage between microchannels.
separating the armatures of capacitor. This change alters the
distribution of electric field, which varies capacitor’s
performances. The microfluidic actuation is used in wide
tunable RF MEMS components [6-9].
The Fig. 1 presents the 3D perspective of our microfluidic
capacitor and the different positions of DI water in
microchannels:

III. CAPACITOR MODELING:
Analytical models describing the operation of microwave
capacitors are generally based on equivalent circuit’s using
lumped and ideals elements and they are generally insufficient
to give fairly and accurate results. Indeed, the obtained results
give an approximation to real behaviors and they not consider
the whole RF losses that are not all taken into account. Furthermore, numerical methods based on the resolution of
Maxwell's equations are more appropriate for RF structures.
There are several types of numerical methods such as finite
difference method (FDM), method of moment (MoM), finite
element method (FEM), etc. During our analyses, we have
chosen FEM software for its high precision of calculation,
although it requires a higher calculation time.
In this part, we expose the effect of DI water displacement on
electric field distribution and current density at 4.5 GHz for
four DI water positions.

1) Electric field distribution:
The Fig 2 shows the surface distribution of electric field at 4.5
GHz in response of dielectric fluid penetration in microchannels:

Figure 1: Design of the squared microfluidic capacitor: (a) 3D
representation of the structure; fluid positions in channel: (b)
POS1 (c) POS2 (d) POS3 (e) POS4.

Figure 2: Surface distribution of electric field at 4.5 GHz for
four DI water positions.
As we can see in Fig. 2 (a), when the capacitor is empty, the electric field is maximal in microchannel and at excitation port 1. Indeed, the permittivity in microchannel (vacuum) is less than that of dielectric medium, which encloses it (substrate and SU-8 layers), and consequently the fluidic channel represents the confinement medium of the electric field. We also note that electric field is high at SU-8 layers that separate spirals and ground. This result shows that electrodes can be considered as a source of electric field prevailing in the structure when it is empty. On the other hand, when the deionized water enters capacitor, it changes the permittivity of the microchannel and subsequently modifies the distribution of the electric field. As we can see in Fig. 2 (b), at first position of fluid, the field decreases in microchannels and remains high in the area closest to electrodes. We also note the appearance of electric field part near the second excitation port. In second position (Fig 2 (c)); the electric field continue to dissipate from microchannels and a residual part remains focused at it. From third position (Figure 2 (d)); we notice an excessive and continuous decrease of E field residual part in microchannels. Indeed, the increase of permittivity in microchannel following the displacement of DI water increasingly influences the depletion of E field in microchannel. The last position of fluid (Fig. 2 (e)) reveals a cancellation of electric field in microchannel and a homogeneous distribution of electric field in structure as well as in the two excitations ports.

2) **Current density distribution:**
The Fig. 3 presents the current density distribution for four DI water positions at 4.5 GHz:

![Figure 3: Current density distribution at 4.5 GHz for four DI water positions.](image)

As we can see in Fig. 3 (a), current density value is low at capacitor center when it is empty. With fluid penetration in microchannels (Figure 3 (b-d)), current density value increases continuously in electrodes and remains zero at the ground surface. At fourth position (Fig. 4 (e)), current density reaches its maximum at electrodes surface and begins to increase at ground surface. We would like to clarify that current density value is mainly related to the operation frequency and reaches its maximum at resonant frequency. Knowing that fluid position in microchannels changes physical properties of the structure and consequently changes the resonant frequency. The results presented in Fig. 3 show a partial current density because the frequency is fixed at 4.5 GHz.

**B. Fluidic variation effect on capacitor performances:**
In this section, we analyze the effect of fluidic actuation on the electrical and RF performances of microfluidic capacitor: capacitance, quality factor, and reflection/transmission losses based on S parameters. The simulation of the structure is carried out under “HFSS-software” for a frequency range from 10 MHz to 40 GHz for four positions of DI water between capacitor's electrodes.

1) **Capacitance and quality factor:**
The Fig. 4 below shows the variation of capacitance and quality as a function of frequency for four positions of DI water:

![Graph showing capacitance and quality factor](image)
The curves of FIG. 4(a) show that the capacitance value increases exponentially in response of frequency up to resonant frequency ($F_{res}$); from there, capacitance value decreases and becomes negative. This change of sign indicates a new mode of operation, which becomes inductive.

Furthermore, we note that when the capacitor is empty, its value is minimal and increases with the progress of fluid circulation. This increase is followed by a degradation of quality factor as shown in FIG. 4(b). Indeed, the quality factor reaches its maximum when the capacitor is empty and then it decreases rapidly with DI water displacement.

In order to investigate the effect of fluid variation, we have taken the value of the capacitance and the quality factor at 4.5 GHz for each fluid position. Figure 5 below summarizes the different results:

2) **RF performances analyses:**

The Fig 6 presents the variation of gain dB(S11) and dB(S21) in response of frequency for four DI water positions:

![Figure 4: Capacitor performances in response of frequency for four DI water positions (a) capacitance value (b) quality factor.](image)

![Figure 6: RF performances in response of four DI water positions (a) dB(S11) gain (b) dB(S21) gain.](image)

Fig. 6(a) illustrates the curves of dB(S11) as a function of frequency for the different positions of the fluid. We notice that the resonance frequency is maximum when the capacitance is empty and decreases with DI water penetration in microchannels. Furthermore, Fig. 6(b) shows dB(S21) versus frequency curves for the different positions of the deionized water. It is clear that the frequency band is wider when the capacitor is empty and it decreases as a function of the filling with deionized water. We note that the range of the capacitive mode operation is described by dB(S21) gain.

To better evaluate the resonant frequency variation, we have taken the minimum values of dB(S11) for each position of DI water (Fig. 7).
The resonant frequency is comprised between 19.81 GHz when the capacitor is empty and 5.67 GHz when it is full. We obtain a broad band variation, which is greater than 240%. In addition, insertion loss is comprised between IL = -0.28 dB and IL = -0.14 dB. These results demonstrate a low insertion loss of the microfluidic capacitor for all DI water positions and could be used for high spectral microwave applications.

C. Conclusion

A wide tunable microfluidic RF MEMS capacitor is designed and analyzed. We have used FEM software in order to model the electric field and the current distribution for different DI water displacement. In addition, we have studied different performances of microfluidic capacitor in response of frequency for four DI water positions. The obtained results present an important variation of the capacitance value and a wide band of resonant frequency. Furthermore, the dB(S21) investigations exhibit a low insertion loss for all water positions.

REFERENCES


